BC368_L34Z Datasheet

DiGi Electronics Part Number	BC368_L34Z-DG
Manufacturer	onsemi
Manufacturer Product Number	BC368_L34Z
Description	TRANS NPN 20V 2A TO92-3
Detailed Description	Bipolar (BJT) Transistor NPN 20 V 2 A 45MHz 625 mW Through Hole TO-92-3

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC368_L34Z	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	2 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
20 V	500mV @ 100mA, 1A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10µA (ICBO)	85 @ 500mA, 1V
Power - Max:	Frequency - Transition:
625 mW	45MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 (TO-226AA)	TO-92-3
Base Product Number:	
BC368	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0095

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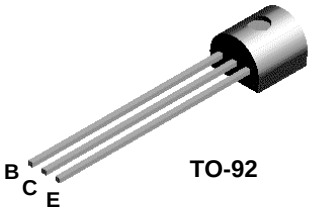
BC368



TO-92

NPN General Purpose Amplifier

This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.5 A. Sourced from Process 37.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	20	V
V_{CES}	Collector-Base Voltage	25	V
V_{EBO}	Emitter-Base Voltage	5.0	V
I_C	Collector Current - Continuous	2.0	A
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:
1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		BC368	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

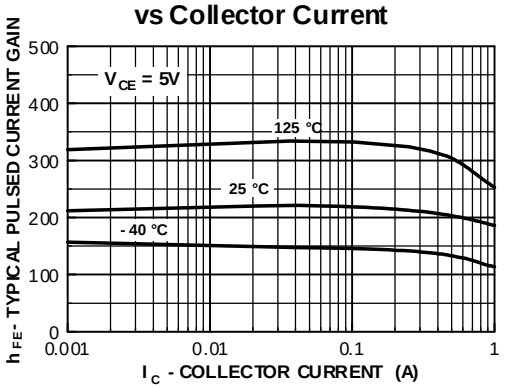
NPN General Purpose Amplifier
(continued)

Electrical Characteristics
TA = 25°C unless otherwise noted

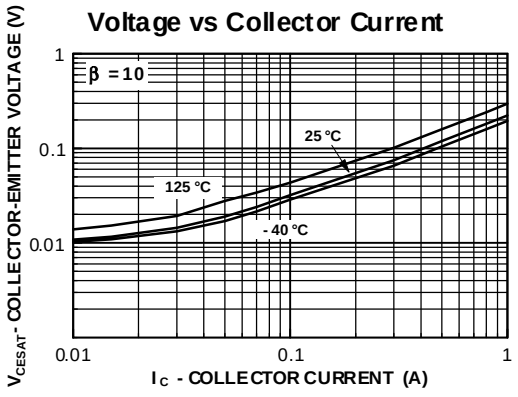
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C = 10 mA, I_B = 0	20		V
$V_{(BR)CES}$	Collector-Base Breakdown Voltage	I_C = 100 μA, I_E = 0	25		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10 μA, I_C = 0	5.0		V
I_{CBO}	Collector-Cutoff Current	V_{CB} = 25 V, I_E = 0 V_{CB} = 25 V, I_E = 0, T_A = 150°C		10 1.0	μA mA
I_{EBO}	Emitter-Cutoff Current	V_{EB} = 5.0 V, I_C = 0		10	μA
ON CHARACTERISTICS					
h_{FE}	DC Current Gain	I_C = 5.0 mA, V_{CE} = 10 V I_C = 0.5 A, V_{CE} = 1.0 V I_C = 1.0 A, V_{CE} = 1.0 V	50 85 60	 375 	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C = 1.0 A, I_B = 100 mA		0.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	I_C = 1.0 A, V_{CE} = 1.0 V		1.0	V
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	I_C = 10 mA, V_{CE} = 5.0 V, f = 35 MHz	45		MHz

Typical Characteristics

Typical Pulsed Current Gain vs Collector Current

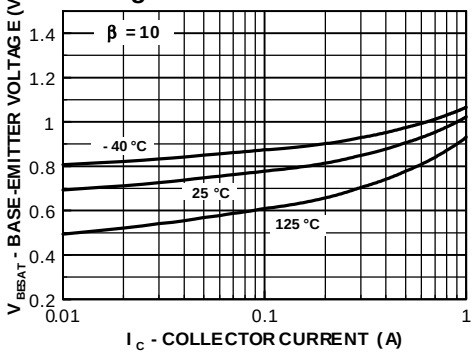


Collector-Emitter Saturation Voltage vs Collector Current

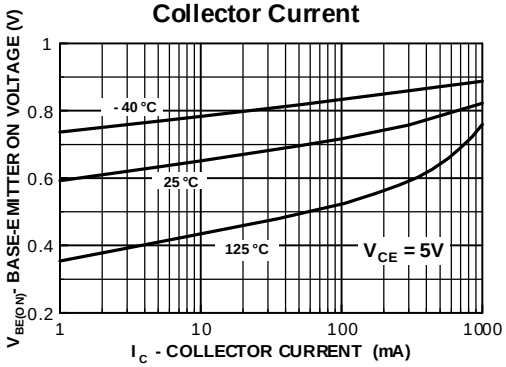


Typical Characteristics (continued)

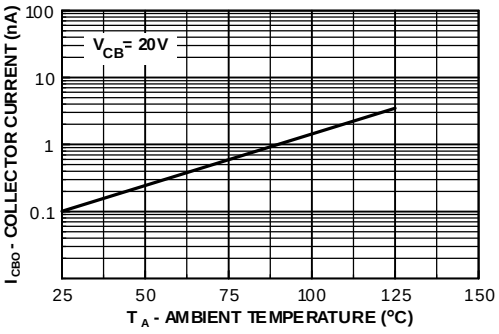
Base-Emitter Saturation Voltage vs Collector Current



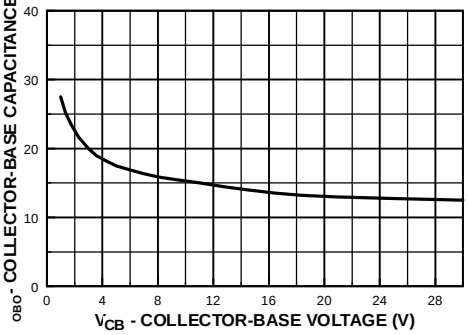
Base-Emitter ON Voltage vs Collector Current



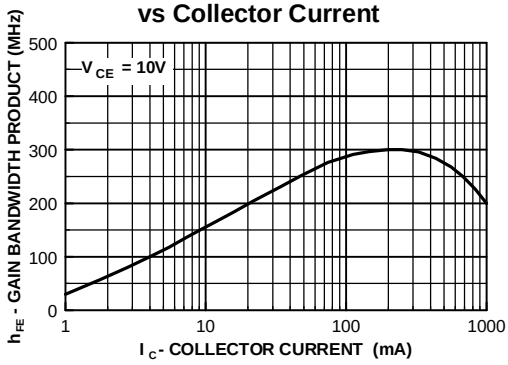
Collector-Cutoff Current vs Ambient Temperature



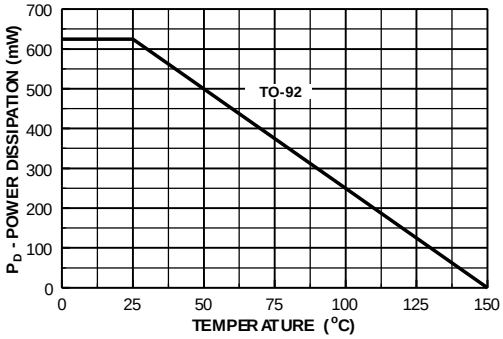
Collector-Base Capacitance vs Collector-Base Voltage



Gain Bandwidth Product vs Collector Current



Power Dissipation vs Ambient Temperature



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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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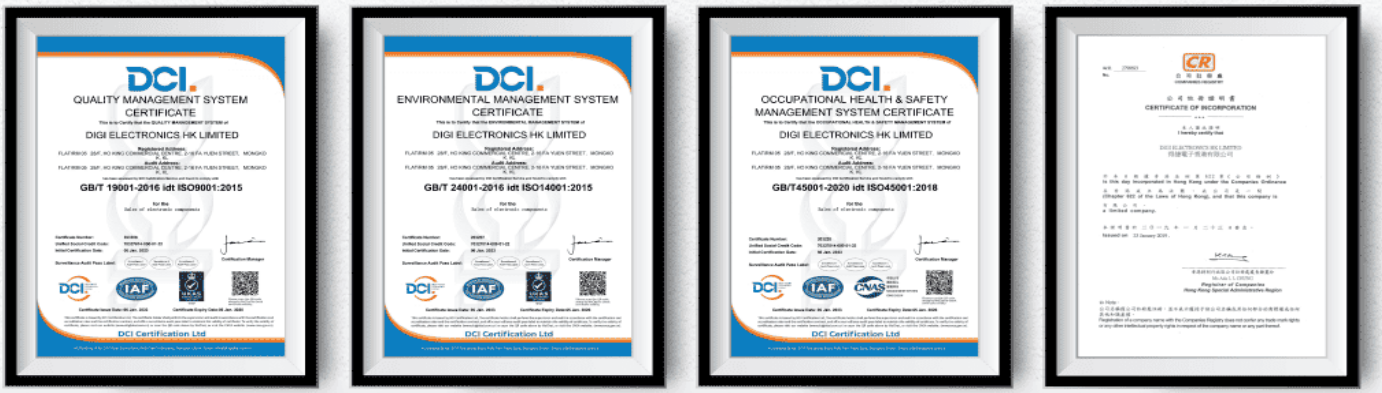

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